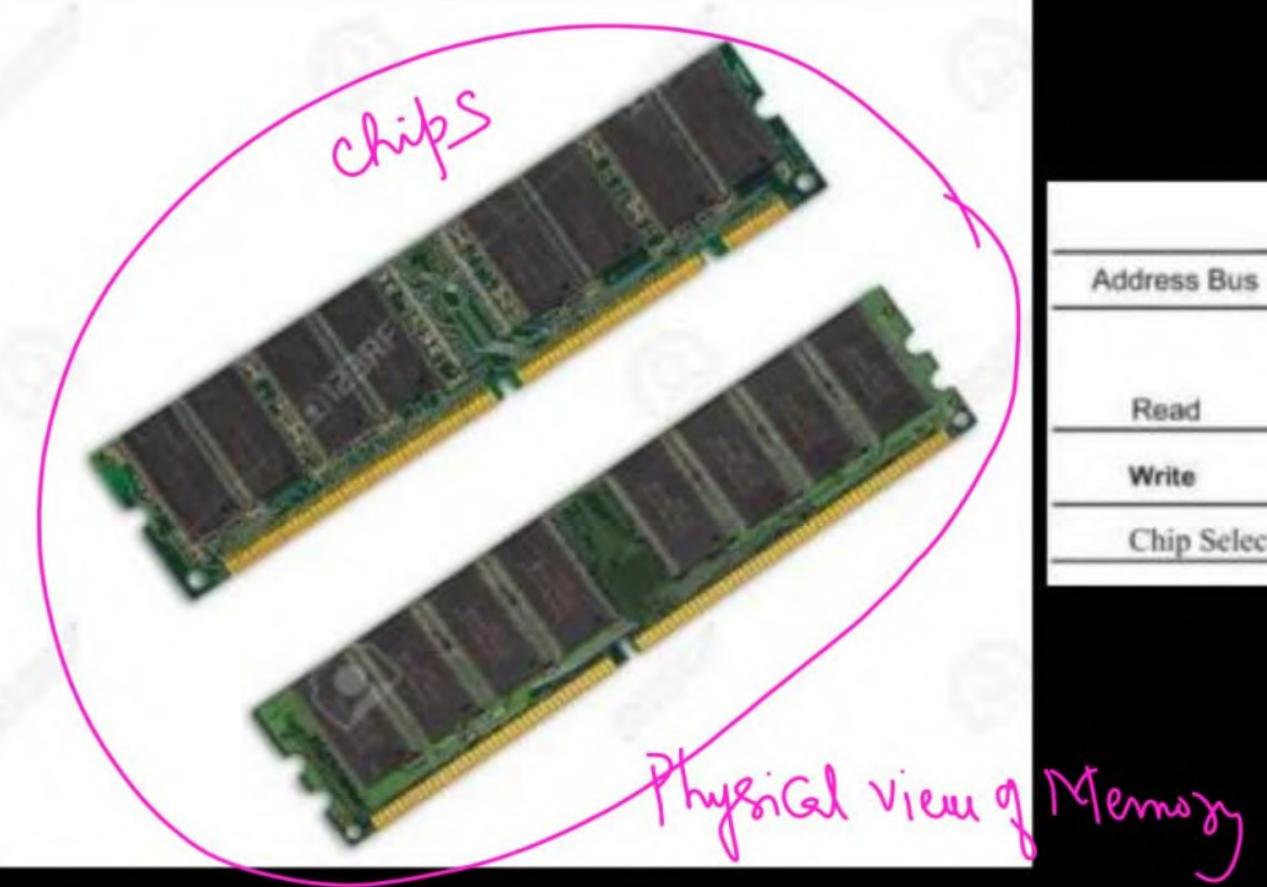




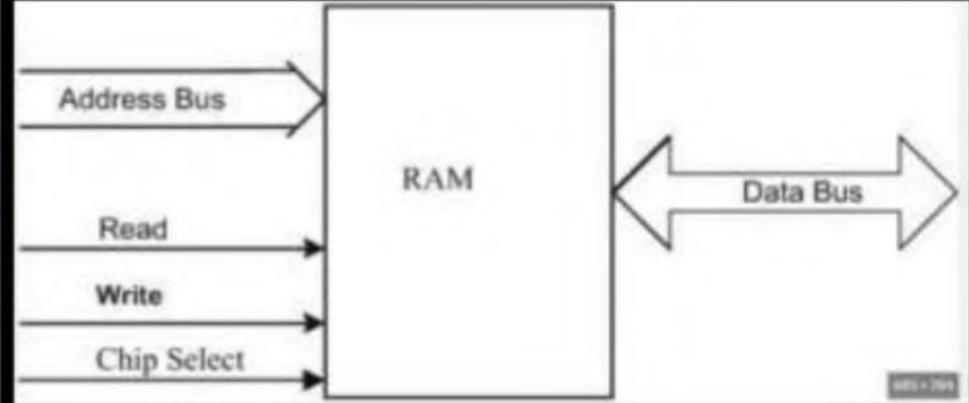




Semiconductor Memory Non-vokTile Volatile! Register Rimasz secondary Slover mary Ceche HDD+ costly RAM; Rom > RAM mm Magnetic) Disk Registers Je conday) Cartineges TD Mem. Hierardy.







Abstract view of Memory Toundation) 8 hits = 1 Byte Addresses 1-Dim-linear Array q words word-length/width of word O words Instry pale Address (n-hits) Locations Cells Word Mem. Specification: Nxm N-1

$$2^{5} = 32W$$
 $2^{2} = 1024 \sim 10 = 1 \text{K}$
 $2^{6} = 64$ $2^{2} = 10^{6} = 1 \text{M}$
 $2^{7} = 128$ $2^{30} \sim 10^{9} = 1 \text{G}$
 $2^{8} = 256$ $2^{40} \sim 10^{12} = 1 \text{T}$
 $2^{1} = 512$ $2^{50} \sim 10^{15} = 1 \text{P}$

$$M = 23 hits$$

$$N = 2^{23} = 2^{3} \times 2^{0} = 8 MW$$

$$N = 100 KW$$

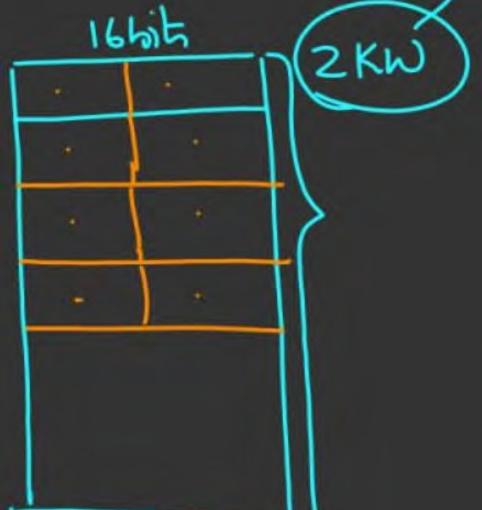
a)
$$m = 19 \text{ hits}$$

 $N = 2^{19} = 2^9 \times 2^{10} = 512 \text{ KW}$

$$m = Log(Log_z^X)$$

a)
$$N = (2KW) = n = 1 + 10 = 11 \text{ hits}$$

 $m = (16 \text{ hits}) | W = 16 \text{ hits} = 2B$

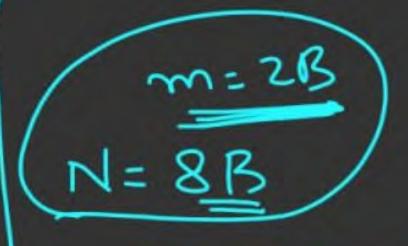


2)
$$m = 16 \text{ hits to refer one word.} \Rightarrow N_w = 2^6 = 64 \text{ KW}$$
 $m = 32 \text{ hils} ; I_w = 32 \text{ hits} = 4B$
 $I_w \rightarrow 4$

$$N_W = \frac{256MB}{8B}$$

$$= \frac{28}{28} = 25 = 32MW$$

$$= \frac{2^3}{2^3} = 2 = 32MW$$



Wo	B 1	۵z
WI	B3	By
Wz	B5	BC
رسا	137	08

$$N_{W} = \frac{239}{27} = 2^{32} = \frac{46W}{46W}$$

